# Product data sheet Characteristics

## XUB5BPANM12

photo-electric sensor - XUB - diffuse - Sn 0.6m - 12..24VDC - M12

#### Main

Commercial Status	Commercialised
Range of product	OsiSense XU
Series name	General purpose single mode
Electronic sensor type	Photo-electric sensor
Sensor name	XUB
Sensor design	Cylindrical M18
Detection system	Diffuse
Material	Metal
Line of sight type	Axial
Type of output signal	Discrete
Supply circuit type	DC
Wiring technique	3-wire
Discrete output type	PNP
Discrete output function	1 NO
Electrical connection	1 male connector M12, 4 pins
Product specific application	-
Emission	Infrared diffuse
[Sn] nominal sensing distance	0.6 m diffuse

#### Complementary

Complementary	
Enclosure material	Nickel plated brass
Lens material	PMMA
Maximum sensing distance	0.8 m diffuse
Output type	Solid state
Add on output	Without
Status LED	1 LED (yellow) for output state
[Us] rated supply voltage	1224 V DC with reverse polarity protection
Supply voltage limits	1036 V DC
Switching capacity in mA	<= 100 mA (overload and short-circuit protection)
Switching frequency	<= 500 Hz
Voltage drop	1.5 V (closed state)
Current consumption	35 mA (no-load)
Delay first up	< 15 ms
Delay response	< 1 ms
Delay recovery	< 1 ms
Setting-up	Sensitivity adjustment
Diameter	18 mm
Length	76 mm
Product weight	0.055 kg

#### Environment

Product certifications	CE CSA UL
Ambient air temperature for operation	-2555 °C
Ambient air temperature for storage	-4070 °C
Vibration resistance	7 gn, amplitude = +/- 1.5 mm (f = 1055 Hz) conforming to IEC 60068-2-6
Shock resistance	30 gn (duration = 11 ms) conforming to IEC 60068-2-27
IP degree of protection	IP65 double insulation conforming to IEC 60529 IP67 double insulation conforming to IEC 60529

### RoHS compliance

RoHS EUR status	Compliant
RoHS EUR conformity date(YYWW)	0814

#### Contractual warranty

Period	18 months	

